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捷多邦，专业PCB打样工厂，24小时加急出货



TR2007SF

Rectifier Diode

## APPLICATIONS

- Rectification
- Freewheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

## KEY PARAMETERS

$V_{RRM}$	4000V
$I_{F(AV)}$	1225A
$I_{FSM}$	25000A

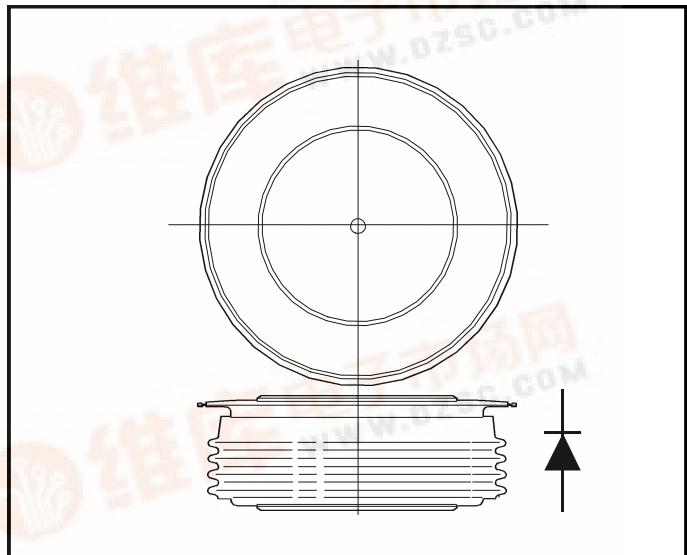
## FEATURES

- Double Side Cooling
- High Surge Capability

## VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage $V_{RRM}$ V	Conditions
TR2007SF40	4000	$V_{RSM} = V_{RRM} + 100V$
TR2007SF39	3900	
TR2007SF38	3800	
TR2007SF37	3700	
TR2007SF36	3600	
TR2007SF35	3500	

Lower voltage grades available.



Outline type code: F.

See Package Details for further information.

## CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
<b>Double Side Cooled</b>				
$I_{F(AV)}$	Mean forward current	Half wave resistive load, $T_{case} = 100^\circ C$	1225	A
$I_{F(RMS)}$	RMS value	$T_{case} = 100^\circ C$	1923	A
$I_F$	Continuous (direct) forward current	$T_{case} = 100^\circ C$	1720	A
<b>Single Side Cooled (Anode side)</b>				
$I_{F(AV)}$	Mean forward current	Half wave resistive load, $T_{case} = 100^\circ C$	820	A
$I_{F(RMS)}$	RMS value	$T_{case} = 100^\circ C$	1287	A
	Continuous (direct) forward current	$T_{case} = 100^\circ C$	1050	A

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## SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
$I_{FSM}$	Surge (non-repetitive) forward current	10ms half sine; $T_{case} = 150^\circ C$ $V_R = 50\% V_{RRM} - 1/4 \sin$	20.0	kA
$I^2t$	$I^2t$ for fusing		$2.0 \times 10^6$	A <sup>2</sup> s
$I_{FSM}$	Surge (non-repetitive) forward current	10ms half sine; $T_{case} = 150^\circ C$ $V_R = 0$	25.0	kA
$I^2t$	$I^2t$ for fusing		$3.125 \times 10^6$	A <sup>2</sup> s

## THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions	Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.022 °C/W
		Single side cooled	Anode dc	-	0.038 °C/W
			Cathode dc	-	0.052 °C/W
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 19.5kN with mounting compound	Double side	-	0.004 °C/W
			Single side	-	0.008 °C/W
$T_{vj}$	Virtual junction temperature	Forward (conducting)	-	160	°C
		Reverse (blocking)	-	150	°C
$T_{stg}$	Storage temperature range		-55	175	°C
-	Clamping force		18.0	22.0	kN

## CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Max.	Units
$V_{FM}$	Forward voltage	At 3400A peak, $T_{case} = 25^\circ C$	-	1.6	V
$I_{RRM}$	Peak reverse current	At $V_{RRM}$ , $T_{case} = 150^\circ C$	-	75	mA
$Q_S$	Total stored charge	$I_F = 2000A$ , $dI_{RR}/dt = 3A/\mu s$ , $T_{case} = 150C$ , $V_R = 100V$	-	3500	μC
$I_{RR}$	Peak recovery current		-	110	A
$V_{TO}$	Threshold voltage	At $T_{vj} = 150C$	-	0.82	V
$r_T$	Slope resistance	At $T_{vj} = 150C$	-	0.29	mΩ

## CURVES

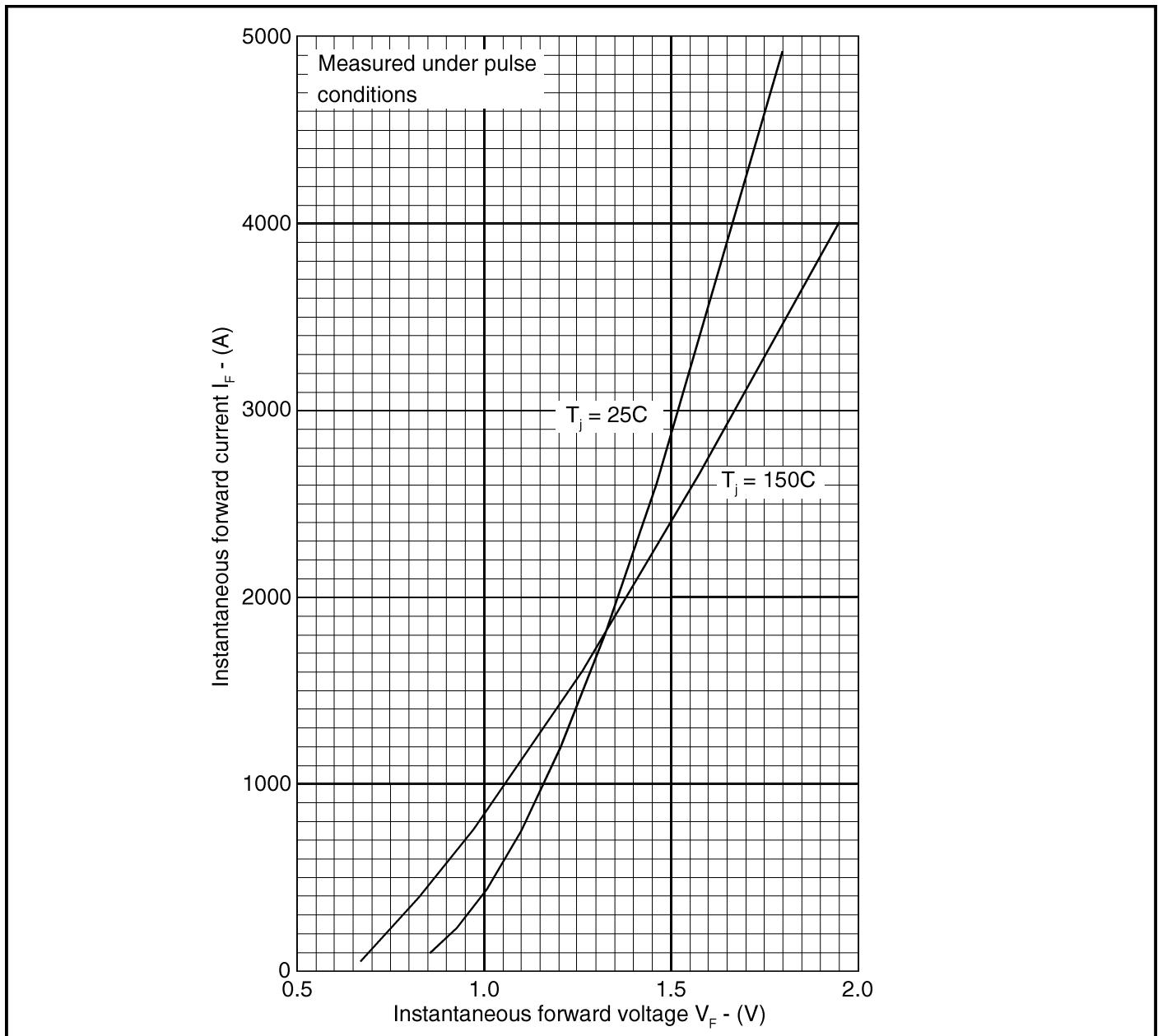
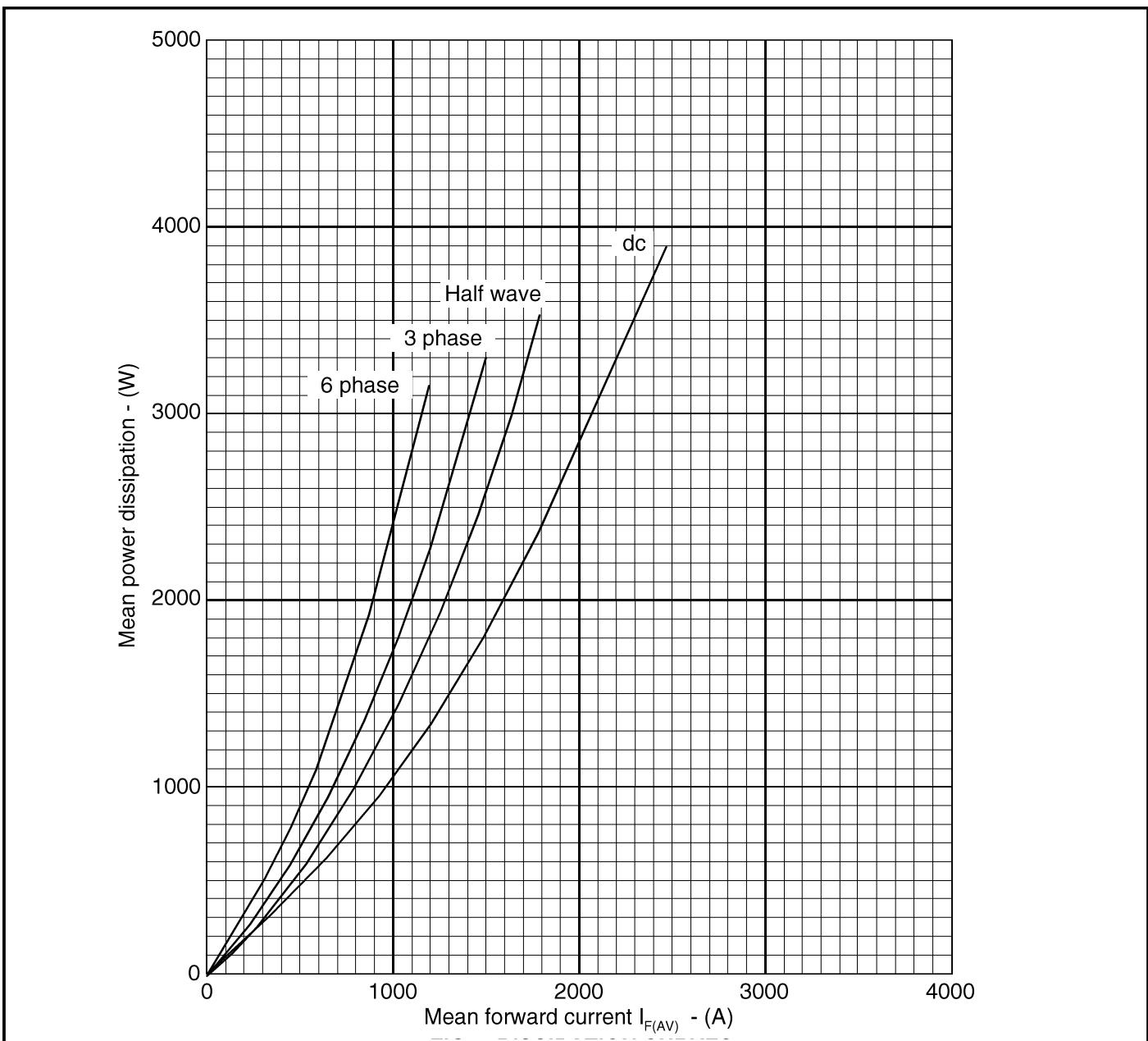


Fig. 1 Maximum (limit) forward characteristics

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**Fig. 2 Dissipation curves**

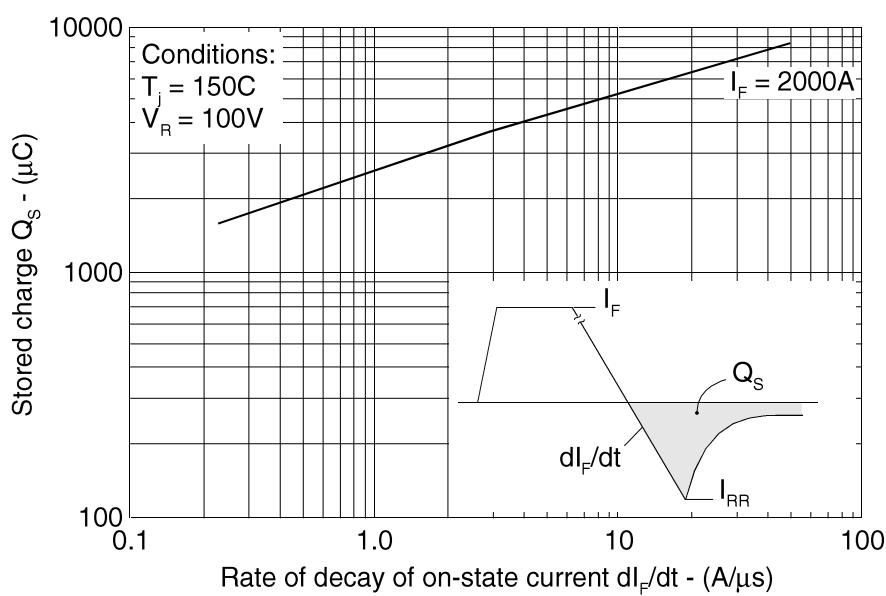


Fig. 3 Maximum total stored charge

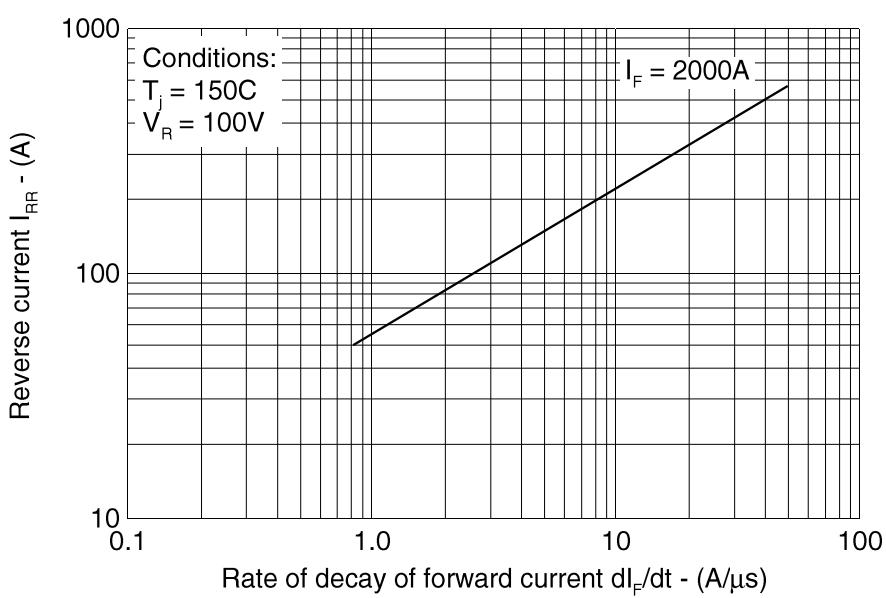


Fig. 4 Maximum reverse recovery current

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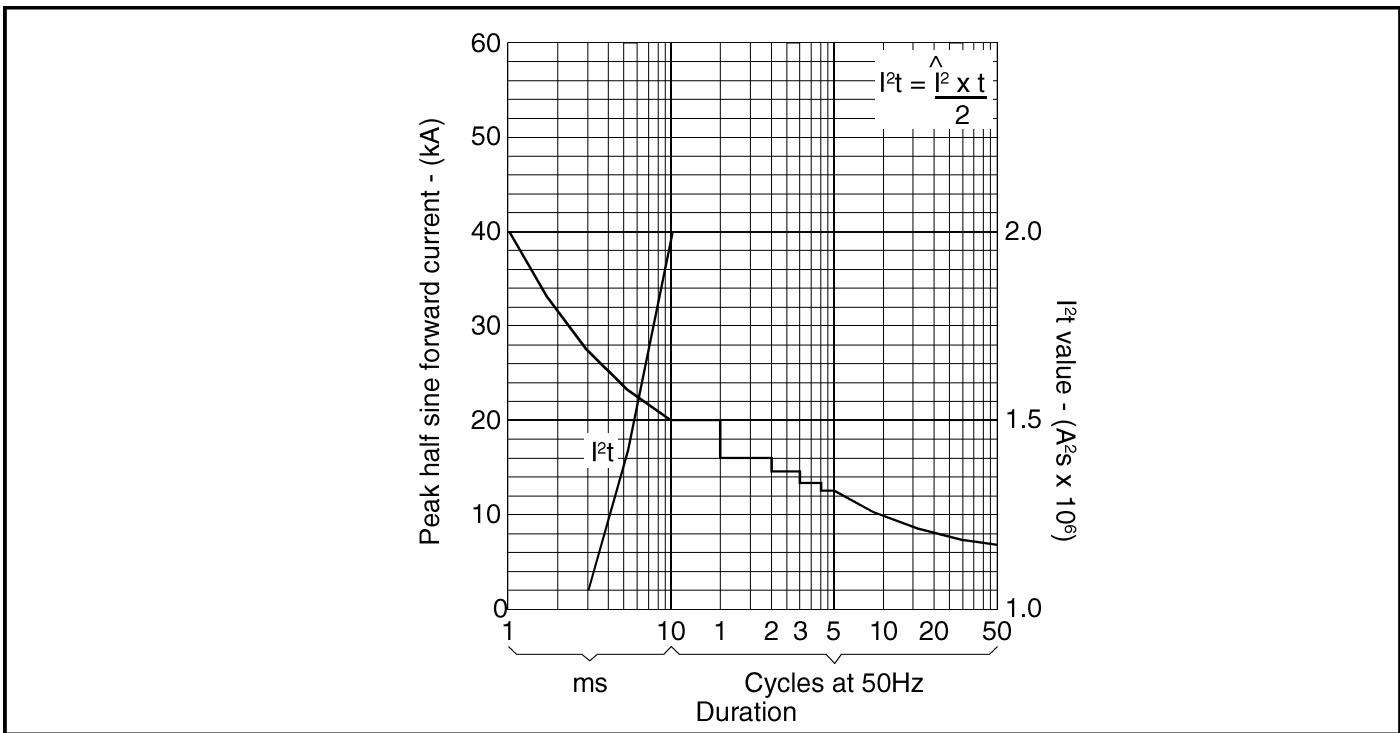


Fig. 5 Surge (non-repetitive) forward current vs time (with 50%  $V_{RRM}$ ,  $T_{case} = 150C$ )

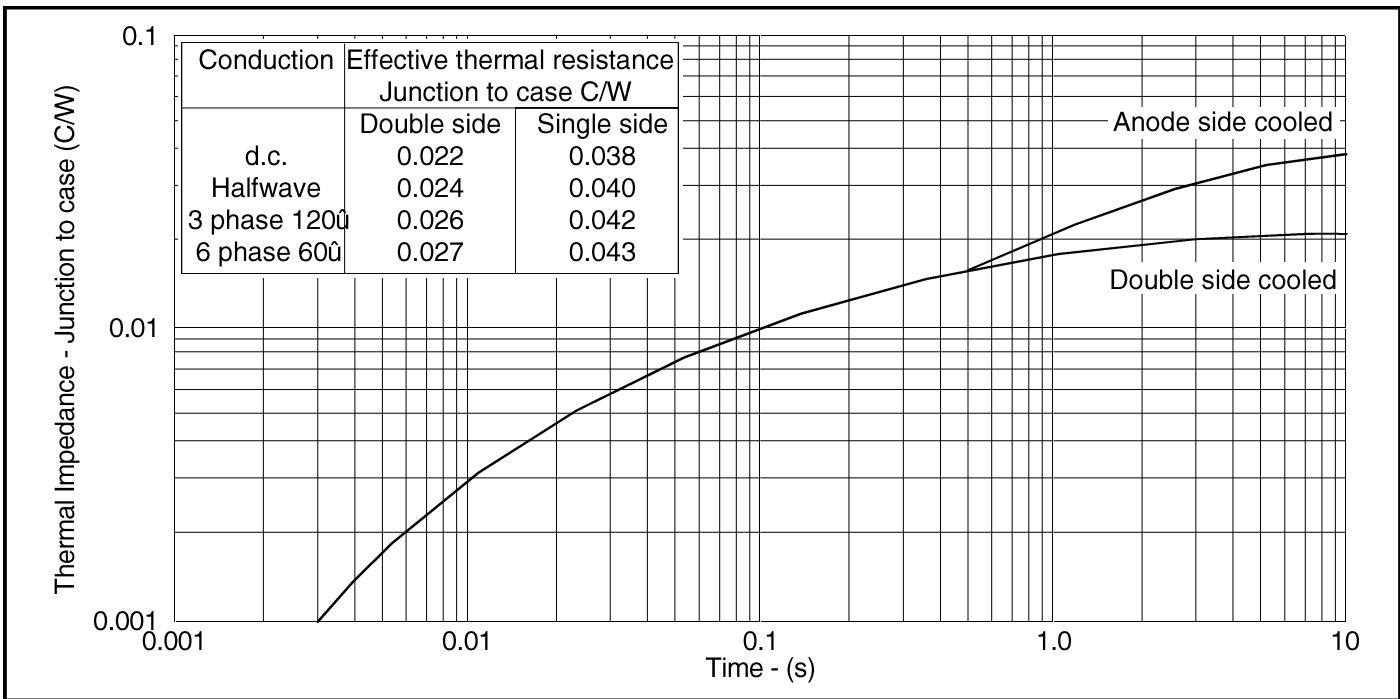


Fig. 6 Transient thermal impedance - junction to case - (C/W)

**PACKAGE DETAILS**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise.  
DO NOT SCALE.

